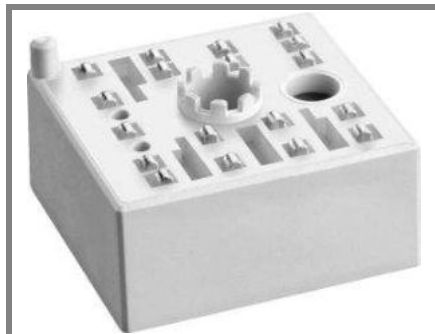




MiniSKiiP® 0

1-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter
SKiiP 03NEC066V3

Features

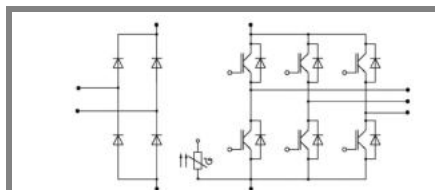
- Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 5,6 kVA
- Typical motor power 3,0 kW

Remarks

- Case temperature limited to $T_C = 125^\circ\text{C}$ max.
- Product reliability results are valid for $T_J = 150^\circ\text{C}$
- SC data: $t_p \leq 6 \mu\text{s}$; $V_{GE} \leq 15 \text{ V}$; $T_J = 150^\circ\text{C}$; $V_{CC} = 360 \text{ V}$
- V_{CEsat} , V_F = chip level value



NEC

Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT - Inverter, Chopper			
V_{CES}		600	V
I_C	$T_s = 25 (70)^\circ\text{C}$, $T_J = 150^\circ\text{C}$	25 (17)	A
I_C	$T_s = 25 (70)^\circ\text{C}$, $T_J = 175^\circ\text{C}$	27 (21)	A
I_{CRM}	$t_p = 1 \text{ ms}$	30	A
V_{GES}		± 20	V
Diode - Inverter, Chopper			
I_F	$T_s = 25 (70)^\circ\text{C}$, $T_J = 150^\circ\text{C}$	24 (16)	A
I_F	$T_s = 25 (70)^\circ\text{C}$, $T_J = 175^\circ\text{C}$	28 (21)	A
I_{FRM}	$t_p = 1 \text{ ms}$	30	A
Diode - Rectifier			
V_{RRM}		800	V
I_F	$T_s = 70^\circ\text{C}$	35	A
I_{FSM}	$t_p = 10 \text{ ms}$, $\sin 180^\circ$, $T_J = 25^\circ\text{C}$	220	A
i^2t	$t_p = 10 \text{ ms}$, $\sin 180^\circ$, $T_J = 25^\circ\text{C}$	240	A ² s
I_{tRMS}	per power terminal (20 A / spring)	20	A
T_J	IGBT, Diode	$-40 \dots +175$	$^\circ\text{C}$
T_{stg}		$-40 \dots +125$	$^\circ\text{C}$
V_{isol}	AC, 1 min.	2500	V

Characteristics		T _s = 25 °C, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Inverter, Chopper					
V _{CE(sat)}	I _{Cnom} = 15 A, T _j = 25 (150) °C		1,45 (1,65)	1,85 (2,05)	V
V _{GE(th)}	V _{GE} = V _{CE} , I _C = 1 mA		5,8		V
V _{CE(TO)}	T _j = 25 (150) °C		0,9 (0,85)	1 (0,9)	V
r _{CE}	T _j = 25 (150) °C		40 (57)	60 (80)	mΩ
C _{ies}	V _{CE} = 25 V, V _{GE} = 0 V, f = 1 MHz		0,86		nF
C _{oes}	V _{CE} = 25 V, V _{GE} = 0 V, f = 1 MHz		0,18		nF
C _{res}	V _{CE} = 25 V, V _{GE} = 0 V, f = 1 MHz		0,12		nF
R _{CC'+EE'}	spring contact-chip T _s = 25 (150)°C				mΩ
R _{th(j-s)}	per IGBT		1,8		K/W
t _{d(on)}	under following conditions		20		ns
t _r	V _{CC} = 300 V, V _{GE} = ± 15V		30		ns
t _{d(off)}	I _{Cnom} = 15 A, T _j = 150 °C		155		ns
t _f	R _{Gon} = R _{Goff} = 22 Ω		45		ns
E _{on} (E _{off})	inductive load		0,6 (0,5)		mJ
Diode - Inverter, Chopper					
V _F = V _{EC}	I _F = 15 A, T _j = 25 (150) °C		1,4 (1,4)	1,7 (1,7)	V
V _(TO)	T _j = 25 (150) °C		1 (0,9)	1,1 (1)	V
r _T	T _j = 25 (150) °C		27 (34)	40 (47)	mΩ
R _{th(j-s)}	per diode		2,5		K/W
I _{RRM}	under following conditions		19,8		A
Q _{rr}	I _{Fnom} = 15 A, V _R = 300 V		1,9		μC
E _{rr}	V _{GE} = 0 V, T _j = 150°C		0,5		mJ
	di _F /dt = 930 A/μs				
Diode - Rectifier					
V _F	I _{Fnom} = 15 A, T _j = 25 °C		1,1		V
V _(TO)	T _j = 150 °C		0,8		V
r _T	T _j = 150 °C		20		mΩ
R _{th(j-s)}	per diode		1,5		K/W
Temperature Sensor					
R _{ts}	3 %, T _r = 25 (100) °C		1000(1670)		Ω
Mechanical Data					
w			21,5		g
M _s	Mounting torque	2		2,5	Nm

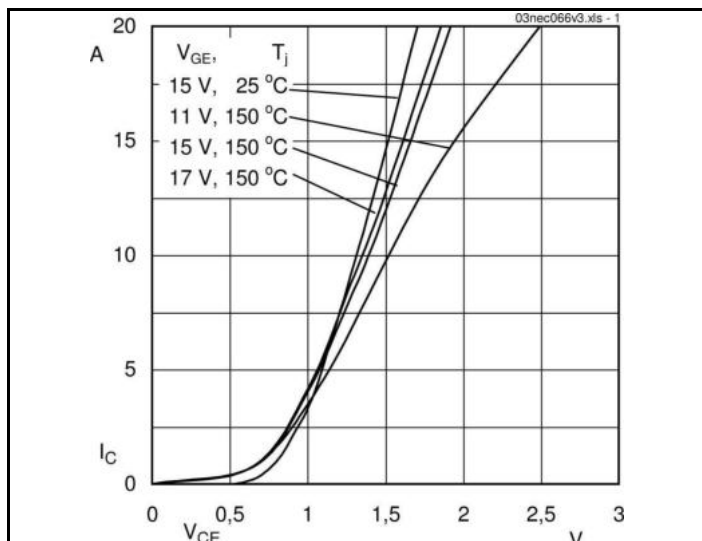


Fig. 1 Typ. output characteristic

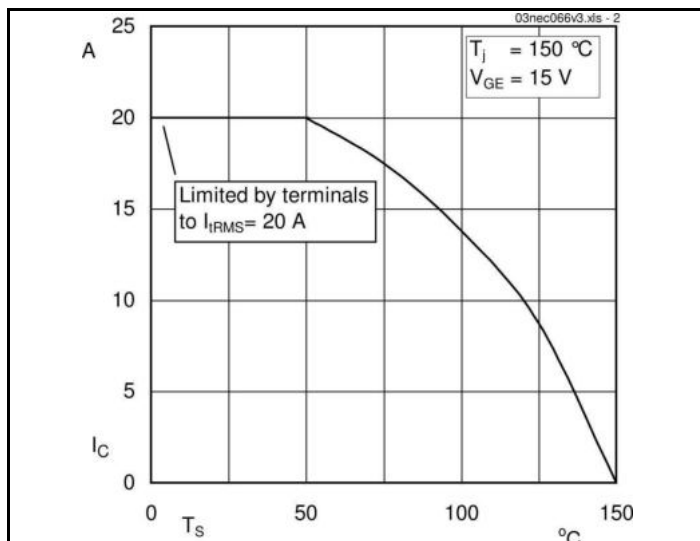


Fig. 2 Typ. rated output current

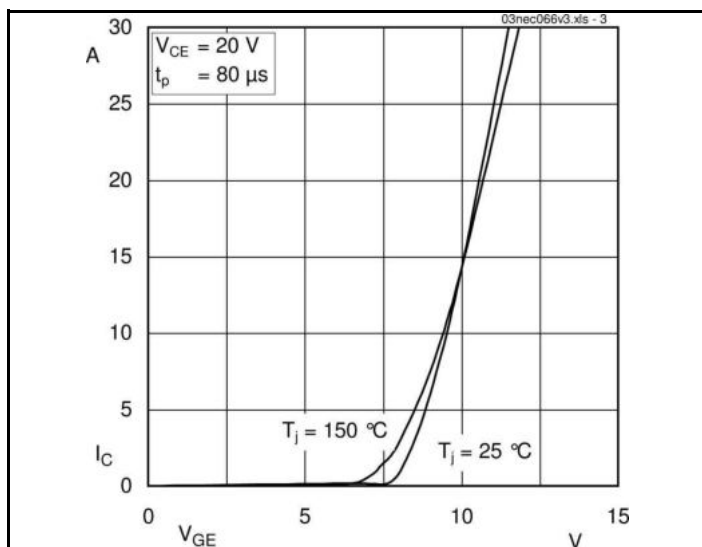


Fig. 3 Typ. transfer characteristic

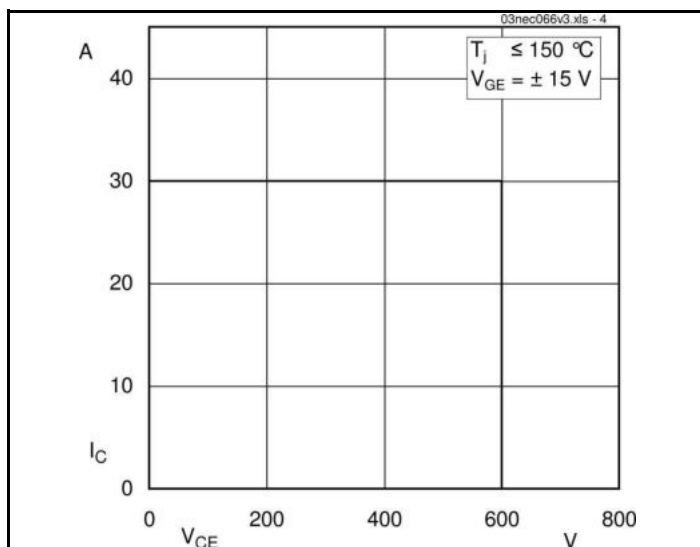


Fig. 4 Reverse bias safe operating area

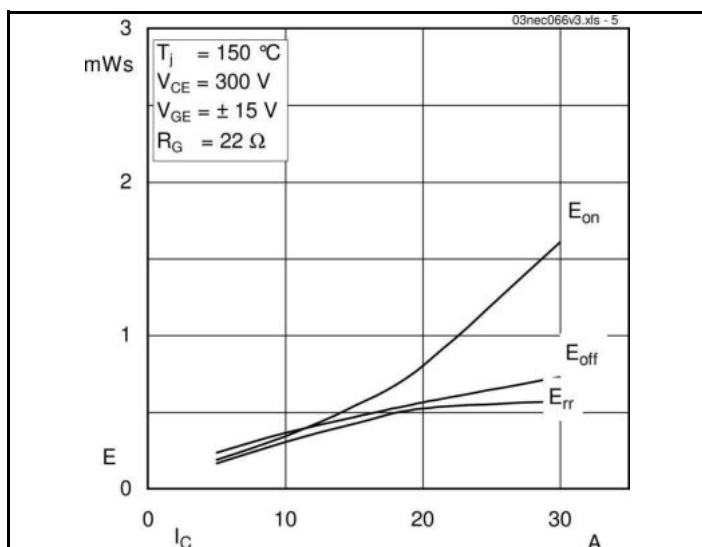


Fig. 5 Typ. Turn-on /-off energy = $f(I_C)$

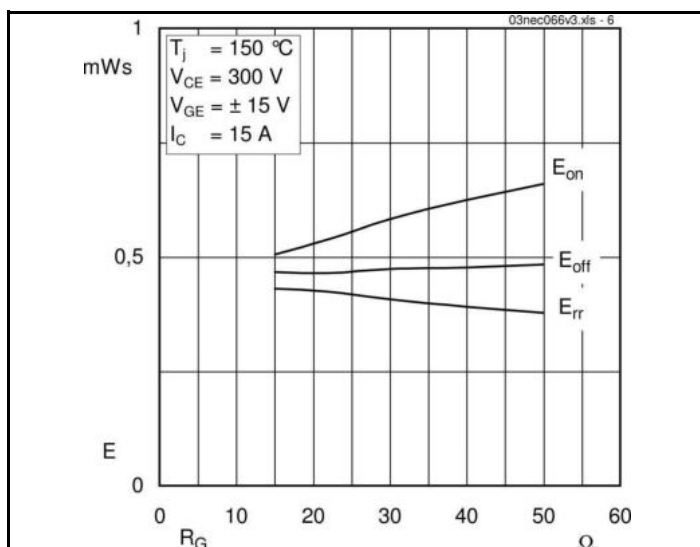
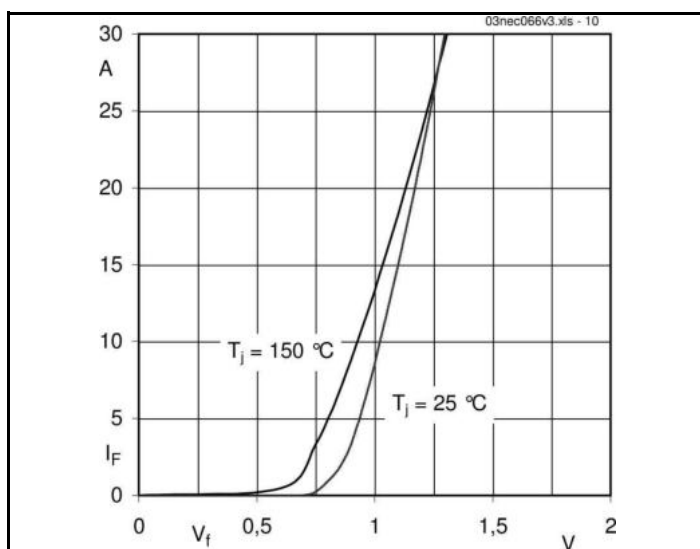
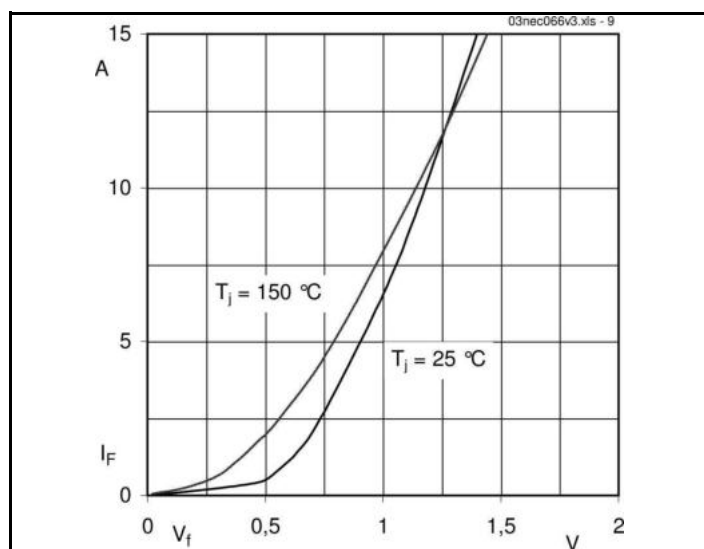
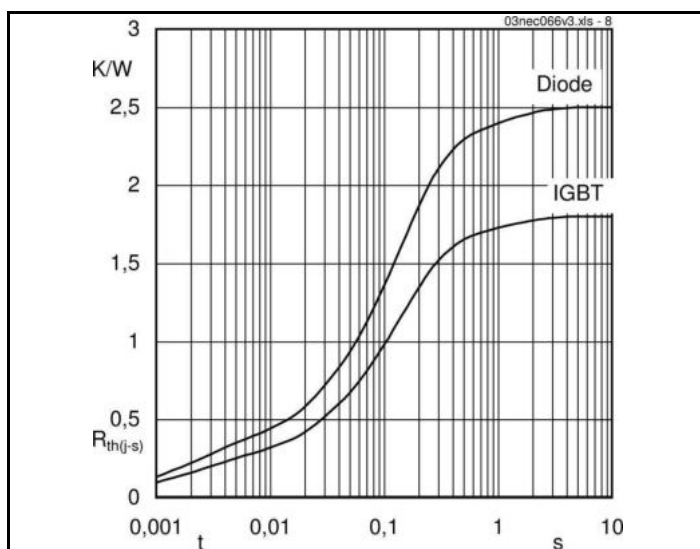
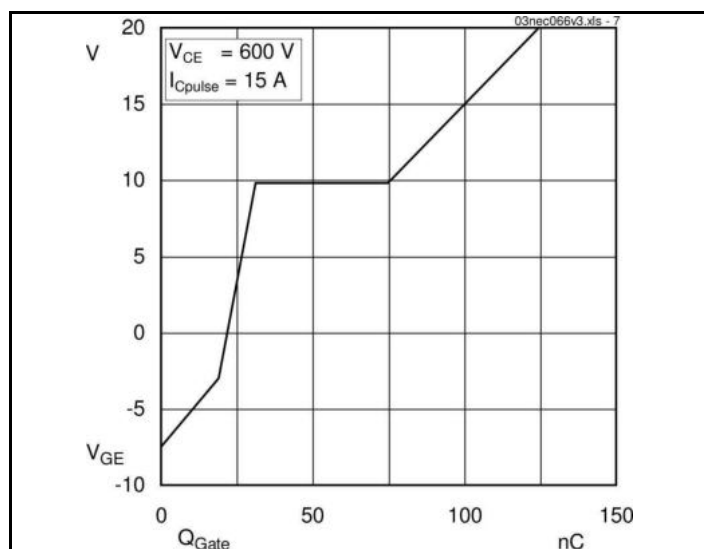
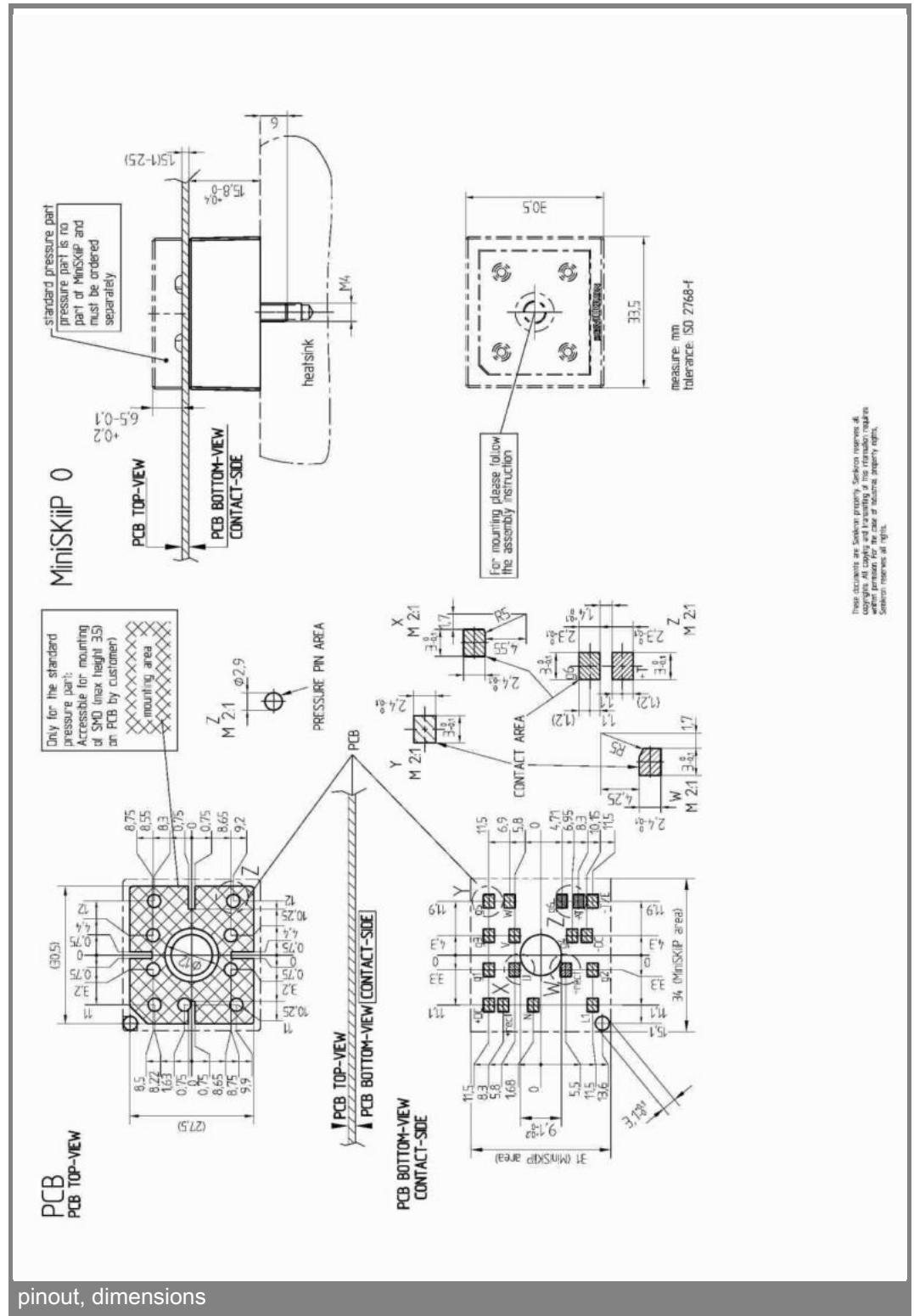
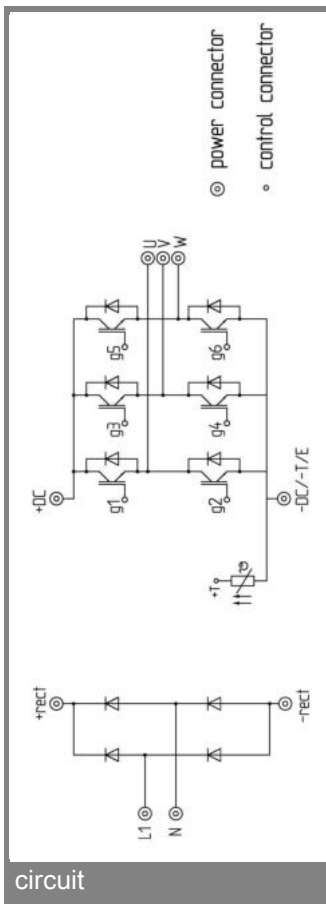


Fig. 6 Typ. Turn-on /-off energy = $f(R_G)$





This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.